

LM35 - Precision Centigrade Temperature Sensor



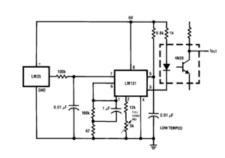
Features

- Calibrated directly in ° Celsius (Centigrade)
- Linear + 10.0 mV/°C scale factor
- 0.5°C accuracy guaranteeable (at +25°C)
- Rated for full -55° to +150°C range
- Suitable for remote applications
- Low cost due to wafer-level trimming
- Operates from 4 to 30 volts
- Less than 60 µA current drain
- Low self-heating, 0.08°C in still air
- Nonlinearity only ±1/4°C typical
- Low impedance output, 0.1 Ohm for 1 mA load

General Description

The LM35 series are precision integrated-circuit temperature sensors, whose output voltage is linearly proportional to the Celsius (Centigrade) temperature.





Parametric Table expand

Cumply Min	4 Volt
Supply Min	4 VOIL
Quiescent Current_	56 uA
Temperature Min	-40, -55, 0 deg C
Temperature Max	100, 110, 150 deg C
Sensor Gain	10 mV/Deg C

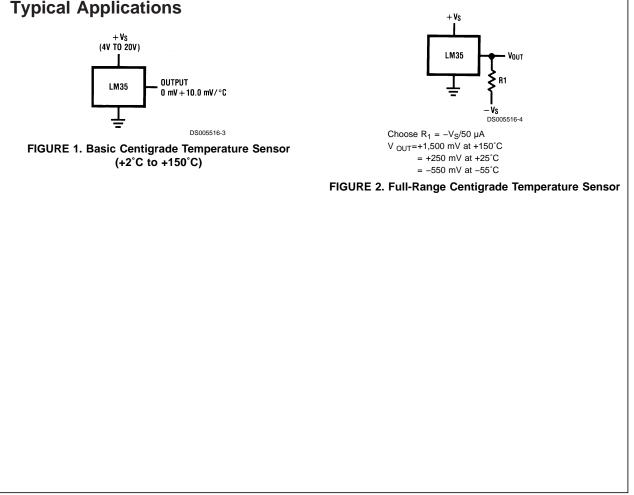
LM35 Precision Centigrade Temperature Sensors

General Description

The LM35 series are precision integrated-circuit temperature sensors, whose output voltage is linearly proportional to the Celsius (Centigrade) temperature. The LM35 thus has an advantage over linear temperature sensors calibrated in Kelvin, as the user is not required to subtract a large constant voltage from its output to obtain convenient Centigrade scaling. The LM35 does not require any external calibration or trimming to provide typical accuracies of ±1/4°C at room temperature and $\pm \frac{3}{4}$ °C over a full -55 to +150°C temperature range. Low cost is assured by trimming and calibration at the wafer level. The LM35's low output impedance, linear output, and precise inherent calibration make interfacing to readout or control circuitry especially easy. It can be used with single power supplies, or with plus and minus supplies. As it draws only 60 µA from its supply, it has very low self-heating, less than 0.1°C in still air. The LM35 is rated to operate over a -55° to $+150^{\circ}$ C temperature range, while the LM35C is rated for a -40° to +110°C range (-10° with improved accuracy). The LM35 series is available packaged in hermetic TO-46 transistor packages, while the LM35C, LM35CA, and LM35D are also available in the plastic TO-92 transistor package. The LM35D is also available in an 8-lead surface mount small outline package and a plastic TO-220 package.

Features

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- Suitable for remote applications
- Low cost due to wafer-level trimming
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- Nonlinearity only ±¼°C typical
- \blacksquare Low impedance output, 0.1 Ω for 1 mA load



Absolute Maximum Ratings (Note 10)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	+35V to -0.2V
Output Voltage	+6V to -1.0V
Output Current	10 mA
Storage Temp.;	
TO-46 Package,	–60°C to +180°C
TO-92 Package,	–60°C to +150°C
SO-8 Package,	–65°C to +150°C
TO-220 Package,	–65°C to +150°C
Lead Temp.:	
TO-46 Package, (Soldering, 10 seconds)	300°C

TO-92 and TO-220 Package, 260°C (Soldering, 10 seconds) SO Package (Note 12) Vapor Phase (60 seconds) 215°C Infrared (15 seconds) 220°C ESD Susceptibility (Note 11) 2500V Specified Operating Temperature Range: $\mathrm{T}_{\mathrm{MIN}}$ to T $_{\mathrm{MAX}}$ (Note 2) LM35, LM35A -55°C to +150°C LM35C, LM35CA -40°C to +110°C LM35D 0° C to +100 $^{\circ}$ C

Electrical Characteristics

(Notes 1, 6)

		LM35A			LM35CA												
Parameter	Conditions	Typical	Tested Limit (Note 4)	Design Limit (Note 5)	Typical	Tested Limit (Note 4)	Design Limit (Note 5)	Units (Max.)									
									Accuracy	T _A =+25°C	±0.2	±0.5		±0.2	±0.5		°C
									(Note 7)	T _A =-10°C	±0.3			±0.3		±1.0	°C
	T _A =T _{MAX}	±0.4	±1.0		±0.4	±1.0		°C									
	T _A =T _{MIN}	±0.4	±1.0		±0.4		±1.5	°C									
Nonlinearity	T _{MIN} ≤T _A ≤T _{MAX}	±0.18		±0.35	±0.15		±0.3	°C									
(Note 8)																	
Sensor Gain	T _{MIN} ≤T _A ≤T _{MAX}	+10.0	+9.9,		+10.0		+9.9,	mV/°C									
(Average Slope)			+10.1				+10.1										
Load Regulation	T _A =+25°C	±0.4	±1.0		±0.4	±1.0		mV/mA									
(Note 3) 0≤l _L ≤1 mA	T _{MIN} ≤T _A ≤T _{MAX}	±0.5		±3.0	±0.5		±3.0	mV/mA									
Line Regulation	T _A =+25°C	±0.01	±0.05		±0.01	±0.05		mV/V									
(Note 3)	4V≤V _S ≤30V	±0.02		±0.1	±0.02		±0.1	mV/V									
Quiescent Current	V _S =+5V, +25°C	56	67		56	67		μA									
(Note 9)	V _s =+5V	105		131	91		114	μA									
	V _S =+30V, +25°C	56.2	68		56.2	68		μA									
	V _s =+30V	105.5		133	91.5		116	μA									
Change of	4V≤V _S ≤30V, +25°C	0.2	1.0		0.2	1.0		μA									
Quiescent Current	4V≤V _S ≤30V	0.5		2.0	0.5		2.0	μA									
(Note 3)																	
Temperature		+0.39		+0.5	+0.39		+0.5	µA/°C									
Coefficient of																	
Quiescent Current																	
Minimum Temperature	In circuit of	+1.5		+2.0	+1.5		+2.0	°C									
for Rated Accuracy	Figure 1, I _L =0																
Long Term Stability	T _J =T _{MAX} , for	±0.08			±0.08			°C									
	1000 hours																

LM35

Electrical Characteristics

(Notes 1, 6)

		LM35			LM35C, LM35D			
Parameter	Conditions		Tested	Design		Tested	Design	Units (Max.)
		Typical	Limit (Note 4)	Limit (Note 5)	Typical	Limit (Note 4)	Limit (Note 5)	
Accuracy,	T _A =+25°C	±0.4	±1.0		±0.4	±1.0		°C
LM35, LM35C	T _A =-10°C	±0.5			±0.5		±1.5	°C
(Note 7)	T _A =T _{MAX}	±0.8	±1.5		±0.8		±1.5	°C
	T _A =T _{MIN}	±0.8		±1.5	±0.8		±2.0	°C
Accuracy, LM35D	T _A =+25°C				±0.6	±1.5		°C
(Note 7)	T _A =T _{MAX}				±0.9		±2.0	°C
	T _A =T _{MIN}				±0.9		±2.0	°C
Nonlinearity	T _{MIN} ≤T _A ≤T _{MAX}	±0.3		±0.5	±0.2		±0.5	°C
(Note 8)								
Sensor Gain	T _{MIN} ≤T _A ≤T _{MAX}	+10.0	+9.8,		+10.0		+9.8,	mV/°C
(Average Slope)			+10.2				+10.2	
Load Regulation	T _A =+25°C	±0.4	±2.0		±0.4	±2.0		mV/mA
(Note 3) 0≤I _L ≤1 mA	T _{MIN} ≤T _A ≤T _{MAX}	±0.5		±5.0	±0.5		±5.0	mV/mA
Line Regulation	T _A =+25°C	±0.01	±0.1		±0.01	±0.1		mV/V
(Note 3)	4V≤V _S ≤30V	±0.02		±0.2	±0.02		±0.2	mV/V
Quiescent Current	V _S =+5V, +25°C	56	80		56	80		μA
(Note 9)	V _s =+5V	105		158	91		138	μA
	V _S =+30V, +25°C	56.2	82		56.2	82		μA
	V _s =+30V	105.5		161	91.5		141	μA
Change of	4V≤V _S ≤30V, +25°C	0.2	2.0		0.2	2.0		μA
Quiescent Current	4V≤V _S ≤30V	0.5		3.0	0.5		3.0	μA
(Note 3)								
Temperature		+0.39		+0.7	+0.39		+0.7	µA/°C
Coefficient of								
Quiescent Current								
Minimum Temperature	In circuit of	+1.5		+2.0	+1.5		+2.0	°C
for Rated Accuracy	Figure 1, I _L =0							
Long Term Stability	T _J =T _{MAX} , for	±0.08			±0.08			°C
	1000 hours							

Note 1: Unless otherwise noted, these specifications apply: $-55^{\circ}C \le T_J \le +150^{\circ}C$ for the LM35 and LM35A; $-40^{\circ} \le T_J \le +110^{\circ}C$ for the LM35C and LM35CA; and $0^{\circ} \le T_J \le +100^{\circ}C$ for the LM35D. $V_S = +5Vdc$ and $I_{LOAD} = 50 \ \mu$ A, in the circuit of *Figure 2*. These specifications also apply from $+2^{\circ}C$ to T_{MAX} in the circuit of *Figure 1*. Specifications in **boldface** apply over the full rated temperature range.

Note 2: Thermal resistance of the TO-46 package is 400°C/W, junction to ambient, and 24°C/W junction to case. Thermal resistance of the TO-92 package is 180°C/W junction to ambient. Thermal resistance of the small outline molded package is 220°C/W junction to ambient. Thermal resistance of the TO-220 package is 90°C/W junction to ambient. For additional thermal resistance information see table in the Applications section.

Note 3: Regulation is measured at constant junction temperature, using pulse testing with a low duty cycle. Changes in output due to heating effects can be computed by multiplying the internal dissipation by the thermal resistance.

Note 4: Tested Limits are guaranteed and 100% tested in production.

Note 5: Design Limits are guaranteed (but not 100% production tested) over the indicated temperature and supply voltage ranges. These limits are not used to calculate outgoing quality levels.

Note 6: Specifications in **boldface** apply over the full rated temperature range.

Note 7: Accuracy is defined as the error between the output voltage and 10mv/°C times the device's case temperature, at specified conditions of voltage, current, and temperature (expressed in °C).

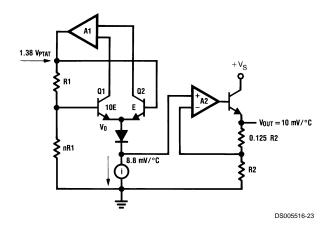
Note 8: Nonlinearity is defined as the deviation of the output-voltage-versus-temperature curve from the best-fit straight line, over the device's rated temperature range.

Note 9: Quiescent current is defined in the circuit of Figure 1.

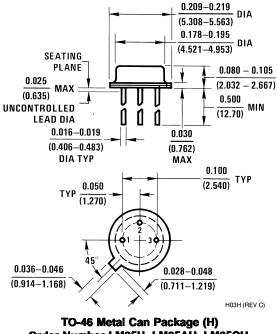
Note 10: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its rated operating conditions. See Note 1.

Note 11: Human body model, 100 pF discharged through a 1.5 $k\Omega$ resistor.

Note 12: See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" or the section titled "Surface Mount" found in a current National Semiconductor Linear Data Book for other methods of soldering surface mount devices.



Physical Dimensions inches (millimeters) unless otherwise noted



Order Number LM35H, LM35AH, LM35CH, LM35CAH, or LM35DH NS Package Number H03H